

RGTH50TK65

650V 25A Field Stop Trench IGBT

V _{CES}	650V
I _{C(100°C)}	16A
V _{CE(sat) (Typ.)}	1.6V@I _C =25A
P_D	59W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

Applications

PFC

UPS

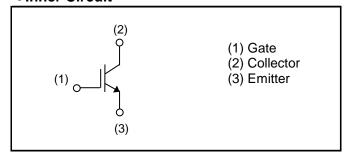
Power Conditioner

ΙH

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTH50TK65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	26	А
	T _C = 100°C	I _C	16	А
Pulsed Collector Current		I _{CP} *1	100	А
Power Dissipation	T _C = 25°C	P_{D}	59	W
	T _C = 100°C	P_{D}	29	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{jmax.}

●Thermal Resistance

Doromotor	Symbol	Values			Unit
Parameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	2.51	°C/W

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
- Farameter Sy		Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	1	-	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, \ V_{CE} = 0V$		-	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 17.5 \text{mA}$	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage		$I_C = 25A, V_{GE} = 15V$				
	V _{CE(sat)}	$T_j = 25$ °C $T_j = 175$ °C	-	1.6	2.1	V
		T _j = 175°C	-	2.1	-	

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Farameter			Min.	Тур.	Max.	Uniii
Input Capacitance	C _{ies}	V _{CE} = 30V	-	1410	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$	-	57	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	22	-	
Total Gate Charge	Q _g	V _{CE} = 300V	-	49	-	
Gate - Emitter Charge	Q_{ge}	I _C = 25A	-	15	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	19	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 25A, V_{CC} = 400V$	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	38	-	no
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	94	-	ns
Fall Time	t _f	Inductive Load	-	50	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 25A, V_{CC} = 400V$	-	27	-	
Rise Time	t _r	$V_{GE} = 15V, R_{G} = 10\Omega$	-	38	-	no
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	107	-	ns
Fall Time	t _f	Inductive Load	-	65	-	
		$I_C = 100A, V_{CC} = 520V$				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650 \text{V}, \ V_{GE} = 15 \text{V}$	FULL SQUARE			-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

Fig.1 Power Dissipation vs. Case Temperature

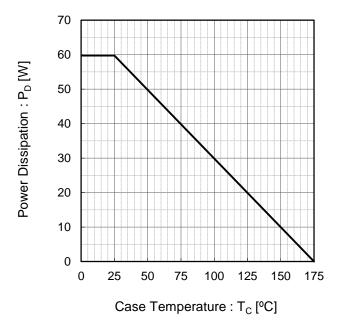
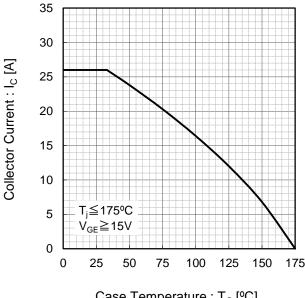
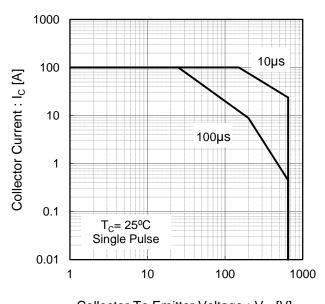


Fig.2 Collector Current vs. Case Temperature



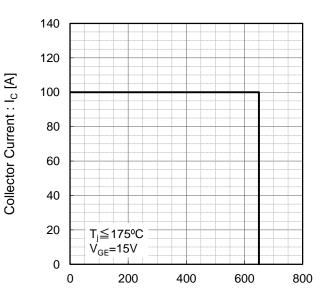
Case Temperature : T_C [°C]

Fig.3 Forward Bias Safe Operating Area



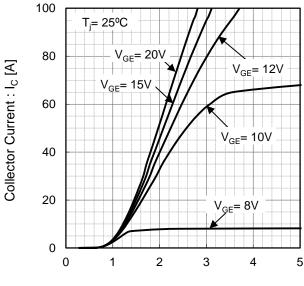
Collector To Emitter Voltage : $V_{CE}[V]$

Fig.4 Reverse Bias Safe Operating Area



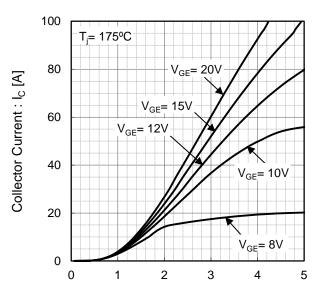
Collector To Emitter Voltage : $V_{CE}[V]$

Fig.5 Typical Output Characteristics



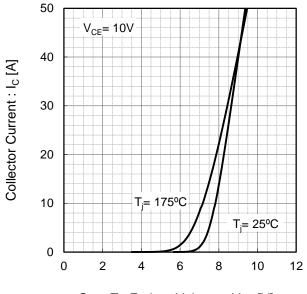
Collector To Emitter Voltage : $V_{CE}[V]$

Fig.6 Typical Output Characteristics



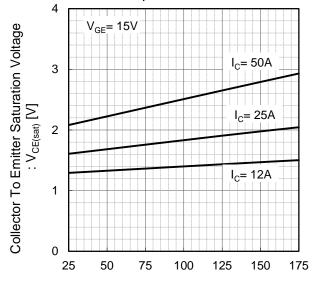
Collector To Emitter Voltage : V_{CE}[V]

Fig.7 Typical Transfer Characteristics



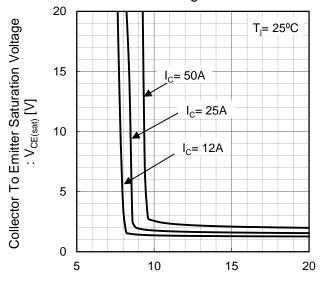
Gate To Emitter Voltage : $V_{GE}[V]$

Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



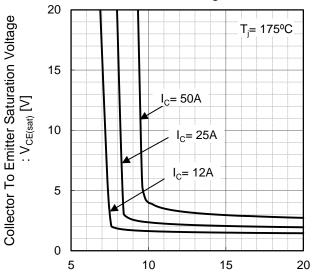
Junction Temperature : T_i [°C]

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage : V_{GE} [V]

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



Gate To Emitter Voltage: V_{GE} [V]

Fig.11 Typical Switching Time vs. Collector Current

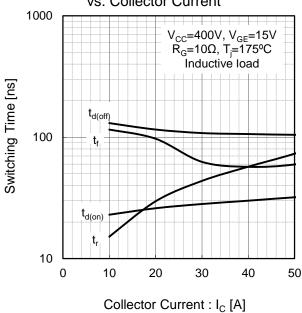
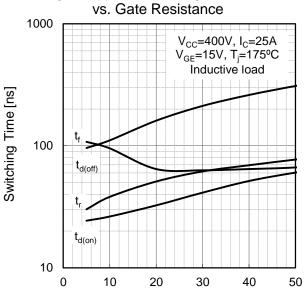


Fig.12 Typical Switching Time



Gate Resistance : $R_G[\Omega]$

Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 E_{off} 0.1 V_{CC} =400V, V_{GE} =15V R_G=10 Ω , T_j=175°C Inductive load 0.01 0 10 30 40 20 50 Collector Current : I_C [A]

vs. Gate Resistance 10 Switching Energy Losses [mJ] $\mathsf{E}_{\mathsf{off}}$ 1 0.1 V_{CC}=400V, I_C=25A V_{GE}=15V, T_j=175°C Inductive load 0.01 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.14 Typical Switching Energy Losses

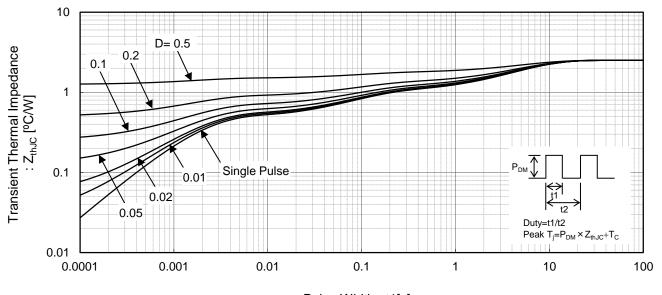
Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] Coes 100 Cres 10 f=1MHz V_{GE}=0V T_i=25°C 0.01 0.1 1 10 100

Collector To Emitter Voltage : V_{CE}[V]

Fig.16 Typical Gate Charge

15 V_{abs} 10 V_{cc} 10 V_{cc} V_{cc} V

Fig.17 IGBT Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

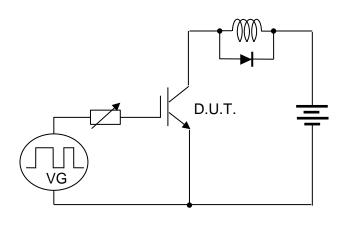


Fig.18 Inductive Load Circuit

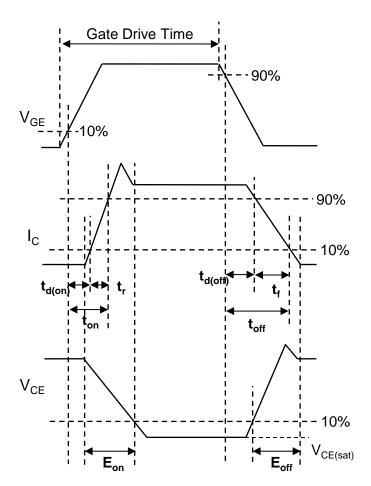


Fig.19 Inductive Load Waveform

Notes

- 1) The information contained herein is subject to change without notice.
- Before you use our Products, please contact our sales representative and verify the latest specifications:
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative: transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM



Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/